DB101S THRU DB107S



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BRIDGE RECTIFIERS		Voltage Range - 50 to 1000 Volts Current -1.0 Ampere							
DBS $\xrightarrow{0.47(1.2)}$ $\xrightarrow{0.35(0.9)}$ $\xrightarrow{-}$	 Features Rating to 1000V PRV Ideal for printed circuit board Low forward voltage drop, high current capability Reliable low cost construction utilizing molded plastic technique results in inexpensive product The plastic material has UL flammability classification 94V-0 Mechanical Data Case: Molded plastic body Polarity: As marked Mounting position : Any Weight: 0.02 ounces, 0.38 grams								
						DIOTI	20		
MAXIMUM RATING Rating at 25°C ambient temperature unless otherwise Single phase, half wave ,60Hz, resistive or inductive For capacitive load, derate current by 20%	e specified		IRICA		RAGIE	KISTI(60		
CHARACTERISTICS	SYMBOL	DB101S	DB102S	DB103S	DB104S	DB105S	DB106S	DB107S	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @Ta=40°C	I(AV)	1.0 A							А
Peak Forward Surge Current									

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Maximum Average Forward	l(AV)	1.0							А
Rectified Current @Ta=40°C	I(AV)		1.0						
Peak Forward Surge Current									
8.3ms Single Half Sine-Wave	IFSM	IFSM 30							А
Super Imposed on Rated Load (JEDEC Method)									l
Maximum Forward Voltage at 1.0A DC	VF	1.1						V	
Maximum DC Reverse Current @TJ=25°C	IR	10 500							μΑ
at Rated DC Bolcking Voltage @TJ=125°C	IR								
I ² t Rating for Fusing(t<8.3ms)	l ² t	10.4						A ² s	
Typical Junction Capacitance Per Element(Note1)	CJ	25						pF	
Typical Thermal Resistance (Note2)	Reja	40						°C/W	
Operating Temperature Range	TJ	-55 to +150						°C	
Storage Temperature Range	Tstg	-55 to +150						°C	
Note:1.Measured at 1.0MHz and applied reverse voltage of 2.Thermal resistance from junction to ambient mounter		with 0.5*0	.5"(13*13r	nm)coppe	pads.				

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